NSN 5962-01-395-0584

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-395-0584

Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
High frequency ra
Features Provided:
Electrostatic sensitive
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Criticality Code Justification:
Cbbl
Terminal Surface Treatment:
Solder
Product Name:
Memory microcircuit
Voltage Rating And Type Per Characteristic:
5.0 volts power source
Memory Device Type:
Ram
Terminal Type And Quantity:
24 printed circuit
Specification Data:
13499-351-8864 manufacturers specification control
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A458a0